DL PACKAGE

(TOP VIEW)

- High-Speed, Low-Skew 1-to-18 Clock Buffer for Synchronous DRAM (SDRAM) Clock **Buffering Applications**
- Output Skew, t_{sk(o)}, Less Than 250 ps
- Pulse Skew, $t_{sk(p)}$, Less Than 500 ps
- Supports up to Four Unbuffered SDRAM **Dual Inline Memory Modules (DIMMs)**
- I²C Serial Interface Provides Individual **Enable Control for Each Output**
- Operates at 3.3 V
- Distributed V_{CC} and Ground Pins Reduce **Switching Noise**
- 100-MHz Operation
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015
- Packaged in 48-Pin Shrink Small Outline (DL) Package

description

The CDC318A is a high-performance clock buffer designed to distribute high-speed clocks in PC applications. This device distributes one input (A) to 18 outputs (Y) with minimum skew for clock distribution. The CDC318A operates from a 3.3-V power supply. It is characterized for operation from 0°C to 70°C.

This device has been designed with consideration for optimized EMI performance. Depending on the application layout, damping resistors in series to the clock outputs (like proposed in the PC100 specification) may not be needed in most cases.

48 NC NC NC 2 47 NC V_{CC}**∏** з 46 V_{CC} 1Y0 4 45 4Y3 1Y1 **5** 44 🛮 4Y2 43 GND GND 6 V_{CC}**□** 7 42 V_{CC} 1Y2 8 41 4Y1 1Y3 9 40 4Y0 39 GND GND 10 38 OE A**II** 11 37 V_{CC} V_{CC} 12 2Y0 13 36 3Y3 35 3Y2 2Y1 14 GND 15 34 GND 33 V_{CC} V_{CC} 16 2Y2 17 32 3Y1 2Y3**∏** 18 31 **∏** 3Y0 GND ∏ 19 30 | GND 29 V_{CC} V_{CC} 20 5Y0**∏**21 28**∏** 5Y1 27 GND GND 22 26 GND V_{CC} 23 25 SCLOCK SDATA 1 24

NC - No internal connection

The device provides a standard mode (100K-bits/s) I²C serial interface for device control. The implementation is as a slave/receiver. The device address is specified in the I²C device address table. Both of the I²C inputs (SDATA and SCLOCK) are 5-V tolerant and provide integrated pullup resistors (typically 140 kΩ).

Three 8-bit I²C registers provide individual enable control for each of the outputs. All outputs default to enabled at powerup. Each output can be placed in a disabled mode with a low-level output when a low-level control bit is written to the control register. The registers are write only and must be accessed in sequential order (i.e., random access of the registers is not supported).

The CDC318A provides 3-state outputs for testing and debugging purposes. The outputs can be placed in a high-impedance state via the output-enable (OE) input. When OE is high, all outputs are in the operational state. When OE is low, the outputs are placed in a high-impedance state. OE provides an integrated pullup resistor.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

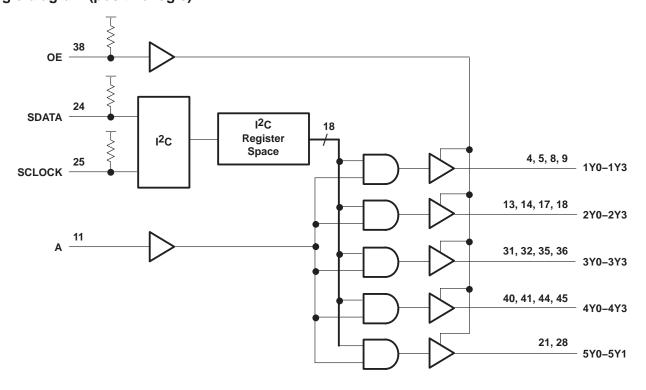


FUNCTION TABLE

INP	UTS			OUTPUTS		
OE	Α	1Y0-1Y3	2Y0-2Y3	3Y0-3Y3	4Y0-4Y3	5Y0-5Y1
L	Χ	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z
Н	L	L	L	L	L	L
Н	Н	н†	н†	н†	н†	н†

[†] The function table assumes that all outputs are enabled via the appropriate I²C configuration register bit. If the output is disabled via the appropriate configuration bit, then the output is driven to a low state, regardless of the state of the A input.

logic diagram (positive logic)





Terminal Functions

-	TERMINAL				
NAME	NO.	I/O	DESCRIPTION		
1Y0-1Y3	4, 5, 8, 9	0	3.3-V SDRAM byte 0 clock outputs		
2Y0-2Y3	13, 14, 17, 18	0	3.3-V SDRAM byte 1 clock outputs		
3Y0-3Y3	31, 32, 35, 36	0	3.3-V SDRAM byte 2 clock outputs		
4Y0-4Y3	40, 41, 44, 45	0	3.3-V SDRAM byte 3 clock outputs		
5Y0-5Y1	21, 28	0	3.3-V clock outputs provided for feedback control of external phase-locked loops (PLLs)		
А	11	I	Clock input		
OE	38	I	Output enable. When asserted, OE puts all outputs in a high-impedance state. A nominal 140 -k Ω pullup resistor is internally integrated.		
SCLOCK	25	I	I ² C serial clock input. A nominal 140-kΩ pullup resistor is internally integrated.		
SDATA	24	I/O	Bidirectional I 2 C serial data input/output. A nominal 140-k Ω pullup resistor is internally integrated.		
GND	6, 10, 15, 19, 22, 26, 27, 30, 34, 39, 43		Ground		
NC	1, 2, 47, 48		No internal connection. Reserved for future use.		
Vcc	3, 7, 12, 16, 20, 23, 29, 33, 37, 42, 46		3.3-V power supply		

I²C DEVICE ADDRESS

A7	A6	A5	A4	А3	A2	A1	A0 (R/W)
Н	Н	L	Н	L	L	Н	_

I²C BYTE 0-BIT DEFINITION[†]

BIT	DEFINITION	DEFAULT VALUE
7	2Y3 enable (pin 18)	Н
6	2Y2 enable (pin 17)	Н
5	2Y1 enable (pin 14)	Н
4	2Y0 enable (pin 13)	Н
3	1Y3 enable (pin 9)	Н
2	1Y2 enable (pin 8)	Н
1	1Y1 enable (pin 5)	Н
0	1Y0 enable (pin 4)	Н

 $[\]ensuremath{^{\dagger}}$ When the value of the bit is high, the output is enabled. When the value of the bit is low, the output is forced to a low state. The default value of all bits is high.



I²C BYTE 1-BIT DEFINITION[†]

BIT	DEFINITION	DEFAULT VALUE
7	4Y3 enable (pin 45)	Н
6	4Y2 enable (pin 44)	Н
5	4Y1 enable (pin 41)	Н
4	4Y0 enable (pin 40)	Н
3	3Y3 enable (pin 36)	Н
2	3Y2 enable (pin 35)	Н
1	3Y1 enable (pin 32)	Н
0	3Y0 enable (pin 31)	Н

 $^{^{\}dagger}$ When the value of the bit is high, the output is enabled. When the value of the bit is low, the output is forced to a low state. The default value of all bits is high.

I²C BYTE 2-BIT DEFINITION[†]

BIT	DEFINITION	DEFAULT VALUE
7	5Y1 enable (pin 28)	Н
6	5Y0 enable (pin 21)	Н
5	Reserved	Н
4	Reserved	Н
3	Reserved	Н
2	Reserved	Н
1	Reserved	Н
0	Reserved	Н

[†]When the value of the bit is high, the output is enabled. When the value of the bit is low, the output is forced to a low state. The default value of all bits is high.



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.5 V to 4.6 V
Input voltage range, V _I (see Note 1)	–0.5 V to 4.6 V
Input voltage range, V _I (SCLOCK, SDATA) (see Note 1)	0.5 V to 6.5 V
Output voltage range, V _O (SDATA) (see Note 1)	–0.5 V to 6.5 V
Voltage range applied to any output in the high or power-off state, V _O	0.5 V to V _{CC} +0.5 V
Current into any output in the low state (except SDATA), IO	
Current into SDATA in the low state, I _O	
Input clamp current, I _{IK} (V _I < 0) (SCLOCK)	
Output clamp current, I _{OK} (V _O < 0) (SDATA)	
Package thermal impedance, θ _{JA} (see Notes 2 and 3)	
Storage temperature range, T _{stq}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 - 2. The package thermal impedance is calculated in accordance with EIA/JEDEC Std JESD51, except for through-hole packages, which use a trace length of zero. The absolute maximum power dissipation allowed at T_A = 55°C (in still air) is 1.2 W.
 - 3. Thermal impedance (ΘJA) can be considerably lower if the device is soldered on the PCB board with a copper layer underneath the package. A simulation on a PCB board (3 in. × 3 in.) with two internal copper planes (1 oz. cu, 0.036 mm thick) and 0.071 mm cu (202) in area underneath the package, resulted in ΘJA = 60°C/W. This would allow 1.2 W total power dissipation at TA = 70°C.

recommended operating conditions (see Note 4)

			MIN	TYP	MAX	UNIT
Vcc	3.3-V core supply voltage		3.135		3.465	V
		A, OE	2		V _{CC} +0.3	V
VIH	High-level input voltage	SDATA, SCLOCK (see Note 3)	2.2		5.5	V
		A, OE	-0.3		0.8	V
V _{IL}	Low-level input voltage	SDATA, SCLOCK (see Note 3)	0		1.04	V
IOH	High-level output current	Y outputs			-36	mA
l _{OL}	Low-level output current	Y outputs			24	mA
rį	Input resistance to V _{CC}	SDATA, SCLOCK (see Note 3)		140		kΩ
f(SCL)	SCLOCK frequency				100	kHz
t(BUS)	Bus free time		4.7			μs
t _{su(START)}	START setup time		4.7			μs
th(START)	START hold time		4			μs
tw(SCLL)	SCLOCK low pulse duration		4.7			μs
tw(SCLH)	SCLOCK high pulse duration		4			μs
tr(SDATA)	SDATA input rise time				1000	ns
tf(SDATA)	SDATA input fall time				300	ns
tsu(SDATA)	SDATA setup time		250			ns
^t h(SDATA)	SDATA hold time		20			ns
t _{su(STOP)}	STOP setup time		4			μs
TA	Operating free-air temperature		0		70	°C

NOTE 4: The CMOS-level inputs fall within these limits: V_{IH} min = $0.7 \times V_{CC}$ and V_{IL} max = $0.3 \times V_{CC}$.



CDC318A 1-LINE TO 18-LINE CLOCK DRIVER WITH I²C CONTROL INTERFACE SCAS614A - SEPTEMBER 1998 - REVISED JUNE 2002

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER			TEST CON	IDITIONS	MIN	TYP	MAX	UNIT	
٧ıK	Input clamp voltage	_	V _{CC} = 3.135 V,	I _I = -18 mA			-1.2	V	
Vон	High-level output voltage	Y outputs	V _{CC} = Min to Max,	$I_{OH} = -1 \text{ mA}$	V _{CC} - 0.1 V			V	
		·	V _{CC} = 3.135 V,	I _{OH} = -36 mA	2.4				
		Vautauta	V _{CC} = Min to Max,	I _{OL} = 1 mA			0.1		
V	Low lovel output voltage	Y outputs	$V_{CC} = 3.135 \text{ V},$	$I_{OL} = 24 \text{ mA}$			0.4	V	
VOL	Low-level output voltage	CDATA	Va - 2 425 V	$I_{OL} = 3 \text{ mA}$			0.4	V	
		SDATA	V _{CC} = 3.135 V	$I_{OL} = 6 \text{ mA}$			0.6		
		SDATA	$V_{CC} = 3.135 \text{ V},$	VO = VCC MAX			20	μΑ	
	Lligh lovel cutout current		$V_{CC} = 3.135 \text{ V},$	V _O = 2 V	-54		-126		
ЮН	High-level output current	Y outputs	V _{CC} = 3.3 V,	V _O = 1.65 V		-92		mA	
			V _{CC} = 3.465 V,	V _O = 3.135 V	-21		-46	1	
			V _{CC} = 3.135 V,	V _O = 1 V	49		118		
loL	Low-level output current	Y outputs	$V_{CC} = 3.3 \text{ V},$	V _O = 1.65 V		93		mA	
			V _{CC} = 3.465 V,	V _O = 0.4 V	24		53		
		А					5		
lіН	High-level input current	OE	V _{CC} = 3.465 V,	VI = VCC			20	μА	
		SCLOCK, SDATA					20		
		А					-5		
IIL	Low-level input current	OE	V _{CC} = 3.465 V,	$V_{i} = GND$	-10		-50	μА	
		SCLOCK, SDATA			-10		-50		
loz	High-impedance-state outpo	ut current	$V_{CC} = 3.465 \text{ V},$	$V_O = 3.465 \text{ V or } 0$			±10	μΑ	
loff	Off-state current	SCLOCK, SDATA	$V_{CC} = 0$,	$V_{I} = 0 V \text{ to } 5.5 V$			50	μΑ	
ICC	Supply current		V _{CC} = 3.465 V,	IO = 0		0.2	0.5	mA	
ΔICC	Change in supply current		$V_{CC} = 3.135 \text{ V to } 3.46$ One input at $V_{CC} = 0$. All other inputs at V_{CC}	6 V,			500	μА	
	Dynamic I _{CC} at 100 MHz		$V_{CC} = 3.465 \text{ V},$	C _L = 20 pF,		230		mA	
Cl	Input capacitance		$V_I = V_{CC}$ or GND,	V _C C = 3.3 V		4		pF	
СО	Output capacitance		$V_O = V_{CC}$ or GND,	V _C C = 3.3 V		6		pF	
C _{I/O}	SDATA I/O capacitance		$V_{I/O} = V_{CC}$ or GND,	V _{CC} = 3.3 V		7		pF	



switching characteristics over recommended operating conditions

	PARAMETER		FROM	то	TEST CONDITIONS	MIN	MAX	UNIT
			А	Υ		1.2	4.5	ns
^t PLH	Low-to-high level propagation of	lelay time	SCLOCK↓	SDATA valid	V_{CC} = 3.3 V ±0.165 V, See Figure 3		2	μs
^t PLH	Low-to-high level propagation delay time		SDATA1	Υ	V_{CC} = 3.3 V ±0.165 V, See Figure 3		150	ns
	High-to-low level propagation delay time		А	Υ		1.2	4.5	ns
^t PHL			SCLOCK↓	SDATA valid	V_{CC} = 3.3 V ±0.165 V, See Figure 3		2	μs
tPHL	High-to-low level propagation delay time		SDATA↑	Y	$V_{CC} = 3.3 \text{ V} \pm 0.165 \text{ V},$ See Figure 3		150	ns
^t PZH	Enable time to the high level		05	V		1	7	
tpzL	Enable time to the low level		OE Y			1	7	ns
^t PHZ	Disable time from the high level		OE	Υ		1	7	20
^t PLZ	Disable time from the low level		OE	T		1	7	ns
^t sk(o)	Skew time		А	Υ			250	ps
tsk(p)	Skew time		А	Υ			500	ps
^t sk(pr)	Skew time		А	Υ			1	ns
t _r	Rise time			Υ		0.5	2.2	ns
	Rise time (see Note 5 and	SDATA			$C_L = 10 pF$	6		20
t _r	Figure 3)	SDATA			$C_L = 400 \text{ pF}$		950	ns
t _f	Fall time			Υ		0.5	2.3	ns
4.	Fall time (see Note 5 and	CDATA			C _L = 10 pF	20		
t _f	Figure 3)	SDATA			C _L = 400 pF		250	ns

NOTE 5: This parameter has a lower limit than BUS specification. This allows use of series resistors for current spike protection.

ESD information

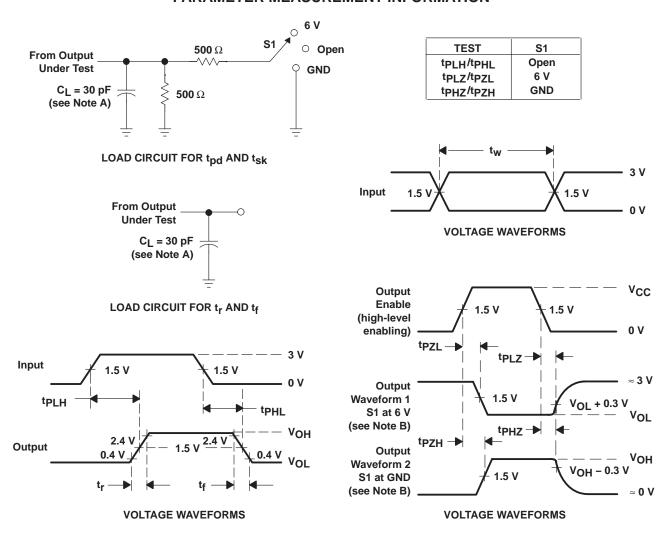
ESD MODELS	LIMIT
Human Body Model (HBM)	2.0 kV
Machine Model (MM)	200 V
Charge Device Model (CDM)	2.0 kV

thermal information

	ODOSAGA AS DIN COOD			THERMAL AIR FLOW (CFM)				
CDC318A 48-PIN SSOP			0	150	250	500	UNIT	
$R_{\theta JA}$	High K		62	56	54	51	°C/W	
$R_{\theta JA}$	Low K		95	71	65	58	°C/W	
$R_{\theta JC}$	High K	36					°C/W	
$R_{\theta JC}$	Low K	38					°C/W	



PARAMETER MEASUREMENT INFORMATION

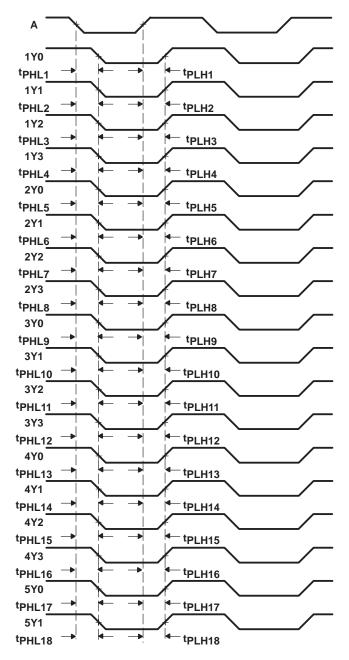


- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2.5 ns. $t_f \leq$ 2.5 ns.
 - D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION



NOTES: A. Output skew, $t_{Sk(0)}$, is calculated as the greater of:

- The difference between the fastest and slowest of tpLHn (n = 1:18)
- The difference between the fastest and slowest of t_{PHLn} (n = 1:18)
- B. Pulse skew, $t_{Sk(p)}$, is calculated as the greater of $|t_{PLHn} t_{PHLn}|$ (n = 1:18)
- C. Process skew, $t_{sk(pr)}$, is calculated as the greater of:
 - The difference between the fastest and slowest of tpLHn (n = 1:18) across multiple devices under identical operating conditions
 - The difference between the fastest and slowest of tpHLn (n = 1:18) across multiple devices under identical operating conditions

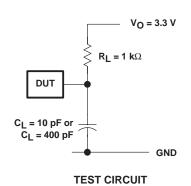
Figure 2. Waveforms for Calculation of $t_{sk(0)}$, $t_{sk(p)}$, $t_{sk(pr)}$



PARAMETER MEASUREMENT INFORMATION

MSB

(S)

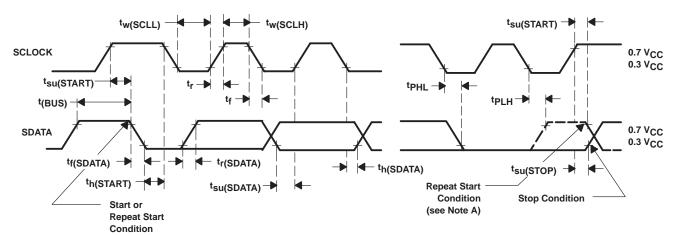


4 to 6 Bytes for Complete Device Programming Bit 0 Stop Start Bit 7 Acknowledge Condition Condition Bit 6 LSB

(R/W)

(A)

(P)



VOLTAGE WAVEFORMS

BYTE	DESCRIPTION
1	I ² C address
2	Command (dummy value, ignored)
3	Byte count (dummy value, ignored)
4	I ² C data byte 0
5	I ² C data byte 1
6	I ² C data byte 2

NOTES: A. The repeat start condition is not supported.

B. All input pulses are supplied by generators having the following characteristics: PRR \leq 100 kHz, $Z_Q = 50~\Omega$, $t_f \geq$ 10 ns, $t_f \geq$ 10 ns.

Figure 3. Propagation Delay Times, t_r and t_f







10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
CDC318ADL	ACTIVE	SSOP	DL	48	25	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	CDC318A	Samples
CDC318ADLG4	ACTIVE	SSOP	DL	48	25	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	CDC318A	Samples
CDC318ADLR	ACTIVE	SSOP	DL	48	1000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	CDC318A	Samples
CDC318ADLRG4	ACTIVE	SSOP	DL	48	1000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	CDC318A	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

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- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





_		
		Dimension designed to accommodate the component width
	B0	Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
ı	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CDC318ADLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1

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*All dimensions are nominal

ĺ	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
	CDC318ADLR	SSOP	DL	48	1000	367.0	367.0	55.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

	Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
	CDC318ADL	DL	SSOP	48	25	473.7	14.24	5110	7.87
Г	CDC318ADLG4	DL	SSOP	48	25	473.7	14.24	5110	7.87

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